

AOZ8831-24

Ultra Low Capacitance One-line
Bi-directional TVS Diode

General Description

The AOZ8831-24 is an ultra low capacitance one-line bi-directional transient voltage suppressor diode designed to protect high speed data lines and voltage sensitive electronics from high transient conditions and ESD.

This device incorporates one TVS diode in an ultra-small DFN 1.0 x 0.6 package. It may be used to meet the ESD immunity requirements of IEC 61000-4-2, Level 4 (±15kV air, ±13kV contact discharge).

The AOZ8831-24 comes in an RoHS compliant DFN package and is rated over a -40°C to +85°C ambient temperature range.

The ultra-small $1.0 \times 0.6 \times 0.4$ mm DFN package makes it ideal for applications where PCB space is a premium. The small size and high ESD protection makes it ideal for protecting voltage sensitive electronics from high transient conditions and ESD.

Features

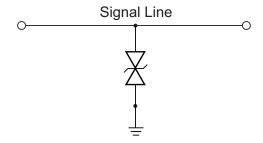
- ESD protection for high-speed data lines:
 - Exceeds: IEC 61000-4-2 (ESD) ±15kV (air), ±13kV (contact)
 - Human Body Model (HBM) ±15kV
- · Small package saves board space
- Ultra low capacitance: 0.35pF
- Low clamping voltage
- · Operating voltage: 24V
- Pb-free device

Applications

- Portable handheld devices
- Notebook computers
- Digital Cameras
- Portable GPS



Typical Application



Bidirection Protection of Single Line

Pin Configuration





Ordering Information

Part Number			Environmental
AOZ8831DT-24	-40°C to +85°C	DFN 1.0 x 0.6	Green Product



AOS Green Products use reduced levels of Halogens, and are also RoHS compliant. Please visit www.aosmd.com/media/AOSGreenPolicy.pdf for additional information.

Absolute Maximum Ratings

Exceeding the Absolute Maximum ratings may damage the device.

Parameter	Rating
VP – VN	24V
Peak Pulse Current (I_{PP}), $t_P = 8/20 \mu s$	1.2A
Peak Pulse Power, t _P = 8/20μs	60W
Storage Temperature (T _S)	-65°C to +150°C
ESD Rating per IEC61000-4-2, Contact ⁽¹⁾	±13kV
ESD Rating per IEC61000-4-2, Air ⁽¹⁾	±15kV
ESD Rating per Human Body Model ⁽²⁾	±15kV

Notes:

- 1. IEC 61000-4-2 discharge with C_Discharge = 150pF, R_Discharge = 330 Ω .
- 2. Human Body Discharge per MIL-STD-883, Method 3015 $C_{Discharge}$ = 100pF, $R_{Discharge}$ = 1.5k Ω .

Maximum Operating Ratings

Parameter	Rating
Junction Temperature (T _J)	-40°C to +125°C

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Electrical Characteristics

 $T_A = 25$ °C unless otherwise specified.

Symbol	Parameter	Diagram					
I _{PP}	Maximum Reverse Peak Pulse Current ⁽³⁾ (100ns Transmission Line Pulse (TLP))	ļ ,					
V _{CL}	Clamping Voltage @ I _{PP} ⁽³⁾	IPP					
V _P	Peak Voltage (IEC61000-4-5 8/20µs, Surge Current I _{PEAK} = 1A)	V _{CL} V _{BR} V _{RWM}					
V _{RWM}	Working Peak Reverse Voltage	VCLVBR VHWM IR VRWM VBR VCL V					
I _R	Maximum Reverse Leakage Current						
V _{BR}	Breakdown Voltage	I _{PP}					
CJ	Capacitance @ V _R = 0 and f = 1MHz	1					

		Device	V _{RWM} (V)	V _{DD} (V)	In (uA)	V _{CL} Max.			V _P (V)		C _J (pF))
Device		Max.				I _{PP} = 2A	I _{PP} = 5A	Max.	Min.	Тур.	Max.	
	AOZ8831DT-24	2	24	26	0.1	38	40	48	45	0.2	0.35	0.5

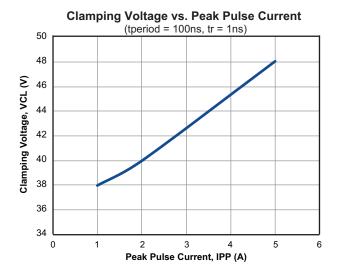
Notes:

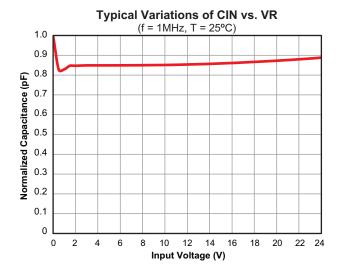
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 $[\]ensuremath{\mathrm{3.}}$ These specifications are guaranteed by design and characterization.



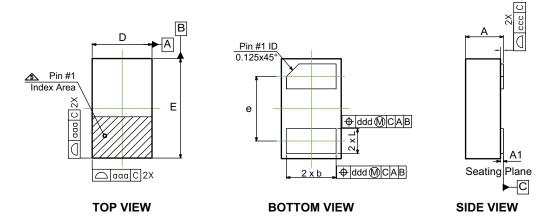
Typical Performance Characteristics



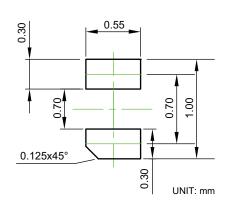




Package Dimensions, DFN 1.0 x 0.6



RECOMMENDED LAND PATTERN



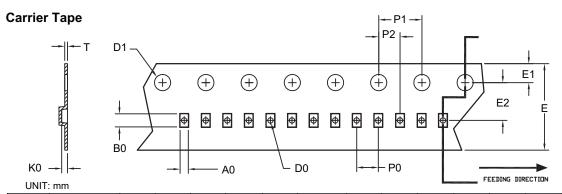
ymbols	Min.	Nom.	Max.	Symbols	Min.	Nom.	Max.		
Α	0.31	0.38 0.40		Α	0.012	0.015	0.016		
A1	0.00	0.02	0.05	A1	0.000	0.001	0.002		
b	0.45 0.50		0.55	b	0.018	0.020	0.022		
D	(0.60 BSC	;	D	0.024 BSC				
E		1.00 BSC		E	0.039 BSC				
е	(0.65 BSC		е	0	.026 BS	С		
L	0.20	0.20 0.25		L	0.008	0.010	0.012		
aaa				aaa		0.002			
CCC		0.03		ccc		0.001			
ddd		0.10		ddd		0.004			

Notes:

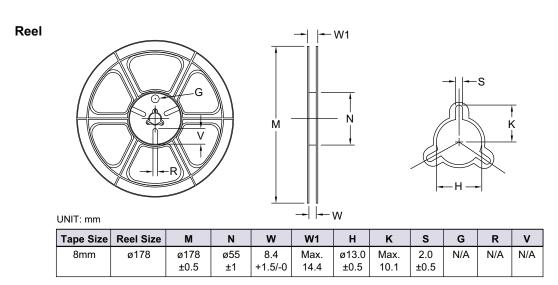
- 1. All dimensions are in millimeters, angles are in degrees.
- 2. Coplanarity applies to the exposed heat sink slug as well as the terminals.

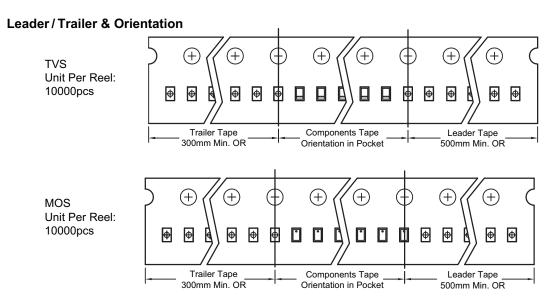


Tape and Reel Dimensions, DFN 1.0 x 0.6



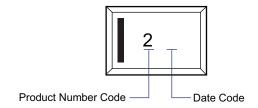
Option	Package	Α0	В0	K0	D0	D1	E	E1	E2	P0	P1	P2	Т
А	DFN 1.0x0.6/ DFN 1.0x0.6A (8 mm)	0.69 ±0.05	1.19 ±0.05	0.66 ±0.05	0.40 ±0.05	1.50 ±0.10	8.00 +0.3/-0.1	1.75 ±0.10	3.50 ±0.05	2.00 ±0.05	4.00 ±0.10	0.20 ±0.05	0.23 ±0.02
В	DFN 1.0x0.6/ DFN 1.0x0.6A (8 mm)	0.65 ±0.04	1.05 ±0.04	0.61 ±0.04	0.40 ±0.05	1.50 ±0.10	8.00 +0.3/-0.1	1.75 ±0.10	3.50 ±0.05	2.00 ±0.10	4.00 ±0.10	0.20 ±0.05	0.20 ±0.05







Part Marking



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